

Zeners 1N5985B - 1N6025B

Absolute Maximum Ratings * T_A = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
P_{D}	Power Dissipation @ TL ≤ 75°C, Lead Length = 3/8"	500	mW
	Derate above 75°C	4.0	mW/°C
T _J , T _{STG}	Operating and Storage Temperature Range	-65 to +200	°C

^{*} These ratings are limiting values above which the serviceability of the diode may be impaired.



Electrical Characteristics TA=25°C unless otherwise noted

	V _Z ((V) @ I _Z (No	Zener Impedanc		er Impedance	leakage Current		(m A)	
Device	Min.	Тур.	Max.	I _Z (mA)	Z _Z @ I _Z (Ω)	Z _{ZK} @ I _{ZK} = 250μA (Ω)	I _R (uA)	V _R (V)	I _{ZM} (mA) (Note 2)
1N5985B	2.58	2.4	2.52	5	100	1800	100	1	208
1N5986B	2.565	2.7	2.835	5	100	1900	75	1	185
1N5987B	2.85	3	3.15	5	95	2000	50	1	167
1N5988B	3.135	3.3	3.465	5	95	2200	25	1	152
1N5989B	3.42	3.6	3.78	5	90	2300	15	1	139
1N5990B	3.705	3.9	4.095	5	90	2400	10	1	128
1N5991B	4.085	4.3	4.515	5	88	2500	5	1	116
1N5992B	4.465	4.7	4.935	5	70	2200	3	1.5	106
1N5993B	4.845	5.1	5.355	5	50	2050	2	2	98
1N5994B	5.32	5.6	5.88	5	25	1800	2	3	89
1N5995B	5.89	6.2	6.51	5	10	1300	1	4	81
1N5996B	6.46	6.8	7.14	5	8	750	1	5.2	74
1N5997B	7.125	7.5	7.875	5	7	600	0.5	6	67
1N5998B	7.79	8.2	8.61	5	7	600	0.5	6.5	61
1N5999B	8.645	9.1	9.555	5	10	600	0.1	7	55
1N6000B	9.5	10	10.5	5	15	600	0.1	8	50
1N6001B	10.45	11	11.55	5	18	600	0.1	8.4	45
1N6002B	11.4	12	12.6	5	22	600	0.1	9.1	42
1N6003B	12.35	13	13.65	5	25	600	0.1	9.9	38
1N6004B	14.25	15	15.75	5	32	600	0.1	11	33
1N6005B	15.2	16	16.8	5	36	600	0.1	12	31
1N6006B	17.1	18	18.9	5	42	600	0.1	14	28
1N6007B	19	20	21	5	48	600	0.1	15	25
1N6008B	20.9	22	23.1	5	55	600	0.1	17	23
1N6009B	22.8	24	25.2	5	62	600	0.1	18	21
1N6010B	25.65	27	28.35	5	70	600	0.1	21	19
1N6011B	28.5	30	31.5	5	78	600	0.1	23	17
1N6012B	31.35	33	34.65	5	88	700	0.1	25	15
1N6013B	34.2	36	37.8	5	95	700	0.1	27	14
1N6014B	37.05	39	40.95	2	130	800	0.1	30	13

Electrical Characteristics (Continued) T_A=25°C unless otherwise noted

	V _Z (V) @ I _Z (Note 1)		Test Current	Zener Impedance		leakage Current		I (A)	
Device	Min.	Тур.	Max.	I _Z (mA)	Z _Z @ I _Z (Ω)	Z _{ZK} @ I _{ZK} = 250μA (Ω)	I _R (uA)	V _R (V)	I _{ZM} (mA) (Note 2)
1N6015B	40.85	43	45.15	2	150	900	0.1	33	12
1N6016B	44.65	47	49.35	2	170	1000	0.1	36	11
1N6017B	48.45	51	53.55	2	180	1300	0.1	39	9.8
1N6018B	53.2	56	58.8	2	200	1400	0.1	43	8.9
1N6019B	58.9	62	65.1	2	225	1400	0.1	47	8
1N6020B	64.6	68	71.4	2	240	1600	0.1	52	7.4
1N6021B	71.25	75	78.75	2	265	1700	0.1	56	6.7
1N6022B	77.9	82	86.1	2	280	2000	0.1	62	6.1
1N6023B	86.45	91	95.55	2	300	2300	0.1	69	5.5
1N6024B	95	100	105	1	500	2600	0.1	76	5
1N6025B	104.5	110	115.5	1	650	3000	0.1	84	4.5

V_F Forward Voltage = 1.2V Max @ I_F = 200mA

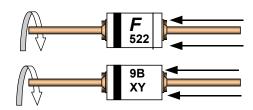
Notes:

1. Zener Voltage (V_Z)
The zener voltage is measured with the device junction in the themal equilibrium at the lead temperature (T_L) at 30°C ± 1°C and 3/8" lead length.

2. Maximum Zener Current Ratings (I_{ZM})
The maximum current handling capability on a worst case basis is limited by the actual zener voltage at the operation point and the power derating curve.

Top Mark Information Line 1 Device Line 2 Line 3 Line 4 1N5985B LOGO 598 5B XY 598 1N5986B LOGO 6B XY 1N5987B LOGO 598 7B XY 1N5988B LOGO 598 8B XY 1N5989B LOGO 598 9B XY 1N5990B LOGO 599 0B ΧY 1N5991B LOGO 599 1B XY 1N5992B LOGO 599 2B XY 1N5993B LOGO 599 3B XY1N5994B LOGO 599 4B XY 1N5995B LOGO 599 5B XY 1N5996B LOGO 599 6B XY LOGO 599 XY1N5997B 7B 1N5998B LOGO 599 8B ΧY 1N5999B LOGO 599 9B XY 1N6000B LOGO 600 0B XΥ 600 1N6001B LOGO 1B XY1N6002B LOGO 600 2B XY 1N6003B LOGO 600 3В XY 1N6004B LOGO 600 4B XY 1N6005B LOGO 600 5B XY 1N6006B LOGO 600 6B XY 1N6007B LOGO 600 7B XY 1N6008B LOGO 600 8B XY LOGO 600 9B 1N6009B XY 1N6010B LOGO 601 0B XY 1N6011B LOGO 601 1B XY 1N6012B **LOGO** 601 2B XY 1N6013B LOGO 3B ΧY 601 1N6014B LOGO 601 4B XY 5B 1N6015B LOGO 601 XY 1N6016B LOGO 601 6B XY 1N6017B LOGO 601 7B XY 1N6018B LOGO 601 8B XY 1N6019B LOGO 601 9B XY 1N6020B LOGO 602 0B XY LOGO 1N6021B 602 1B XY 1N6022B LOGO 602 2B XY 602 1N6023B LOGO 3B XY 1N6024B LOGO 602 4B ΧY 1N6025B LOGO 602 5B XY

Top Mark Information (Continued)



1st line: F - Fairchild Logo

 2^{nd} line: Device Name - 3^{rd} to 5^{th} characters of the device name. or 4^{th} to 6^{th} characters for BZXyy series

3rd line: Device Name - 6th to 7th characters of the device name. or Voltage rating for BZXyy series

4th line: Device Code or - Two Digit - Six Weeks Date Code. Date code plus or Two Digit - Six Weeks Date Code Large die identification plus Large die identification, "L"

General Requirements:

- 1.0 Cathod Band
- 2.0 First Line: F Fairchild Logo
- 3.0 Second Line: Device name For 1Nxx series: 3^{rd} to 5th characters of the device name. For BZxx series: 4^{th} to 6^{th} characters of the device name.
- 4.0 Third Line: Device name For 1Nxx series: 6th to 7th characters of the device name. For BZXyy series: Voltage rating
- 5.0 Fourth Line: XY or XYL Two Digit Six Weeks Date Code

Where: X represents the last digit of the calendar year Y represents the Six weeks numeric code L represents the Large die identification

- 6.0 Devices shall be marked as required in the device specification (PID or FSC Test Spec).
- 7.0 Maximum no. of marking lines: 4
- 8.0 Maximum no. of digits per line: 3
- 9.0 FSC logo must be 20 % taller than the alphanumeric marking and should occupy the 2 characters of the specified line.
- 10.0 Marking Font: Arial (Except FSC Logo)
- 11.0 First character of each marking line must be aligned vertically

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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
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1N6007B

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Product	Product status	Pb-free Status	Pricing*	Package type	Leads	Packing method	Package Marking Convention**
1N6007B	Full Production	Full Production	\$0.0218	DO-35	2		<u>Line 1:</u> \$Y (Fairchild logo) <u>Line 2:</u> 600 <u>Line 3:</u> 7B <u>Line 4:</u> &2
1N6007B_T50A	Full Production	Full Production	N/A	DO-35	2		<u>Line 1:</u> \$Y (Fairchild logo) <u>Line 2:</u> 600 <u>Line 3:</u> 7B <u>Line 4:</u> &2
1N6007B_T50R	Full Production	Full Production	N/A	DO-35	2		<u>Line 1:</u> \$Y (Fairchild logo) <u>Line 2:</u> 600 <u>Line 3:</u> 7B <u>Line 4:</u> &2

^{*} Fairchild 1,000 piece Budgetary Pricing

^{**} A sample button will appear if the part is available through Fairchild's on-line samples program. If there is no sample button, please contact a Fairchild distributor to obtain samples



Indicates product with Pb-free second-level interconnect. For more information click here.

Package marking information for product 1N6007B is available. Click here for more information .

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